

CATV Line Amplifiers/Power Inserters 5 kA *SIDACtor*® Device



This *SIDACtor* device is a 5000 A solid state protection device offered in a non-isolated TO-218 package. It protects equipment located in the severe surge environment of CATV (Community Antenna TV) systems and antenna locations.

Electrical Parameters

Part Number *	V _{DRM} Volts	V _S Volts	V _T Volts	I _{DRM} μAmps	I _S mAmps	I _T Amps **	I _H mAmps
P1500MEL	140	180	4	5	800	2.2/25	50
P1900MEL	140	220	4	5	800	2.2/25	50
P2300MEL	180	260	4	5	800	2.2/25	50

* "L" in part number indicates RoHS compliance. For non-RoHS compliant device, delete "L" from part number.
For surge ratings, see table below.

** I_T is a free air rating; heat sink I_T rating is 25 A.

General Notes:

- All measurements are made at an ambient temperature of 25 °C. I_{PP} applies to -40 °C through +85 °C temperature range.
- I_{PP} is a repetitive surge rating and is guaranteed for the life of the product.
- Listed *SIDACtor* devices are bi-directional. All electrical parameters and surge ratings apply to forward and reverse polarities.
- V_{DRM} is measured at I_{DRM}.
- V_S is measured at 100 V/μs.
- Special voltage (V_S and V_{DRM}) and holding current (I_H) requirements are available upon request.

Surge Ratings in Amps

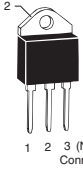
Series	I _{PP}	I _{TSM} 50 / 60 Hz	di/dt
	8x20 * 1.2x50 **		
	Amps	Amps	Amps/μs
E	5000	400	630

* Current waveform in μs

** Voltage waveform in μs

SIDACtor Devices

Thermal Conditions

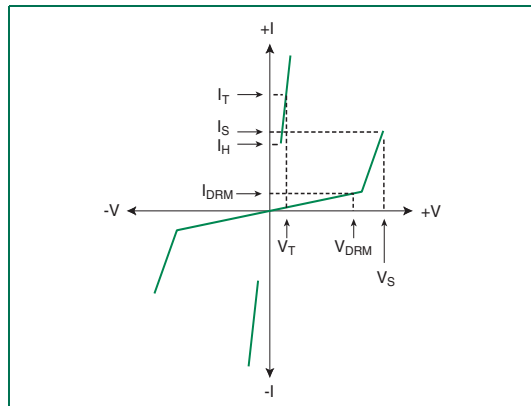
Package	Symbol	Parameter	Value	Unit
TO-218 	T_J	Operating Junction Temperature Range	-40 to +150	°C
	T_S	Storage Temperature Range	-65 to +150	°C
	T_C	Maximum Case Temperature	100	°C
	$R_{\theta JC}^*$	Thermal Resistance: Junction to Case	1.7	°C/W
	$R_{\theta JA}$	Thermal Resistance: Junction to Ambient	56	°C/W

$R_{\theta JC}$ rating assumes the use of a heat sink and on state mode for extended time at 25 A, with average power dissipation of 29.125 W.

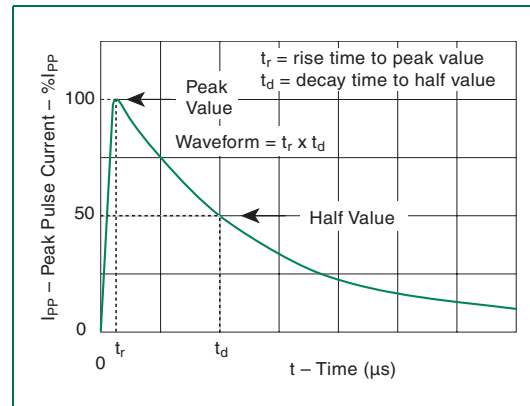
Capacitance Values

Part Number	pF	
	MIN	MAX
P1500MEL	400	650
P1900MEL	400	650
P2300MEL	350	600

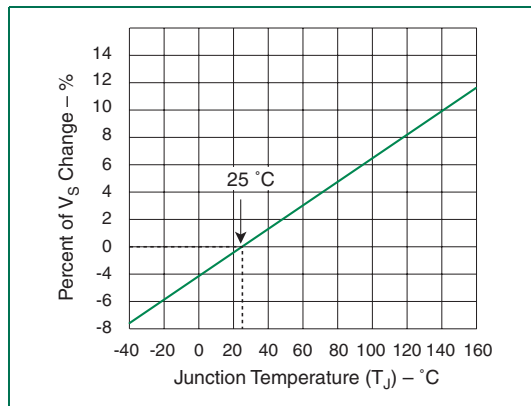
Note: Off-state capacitance (C_O) is measured at 1 MHz with a 2 V bias.



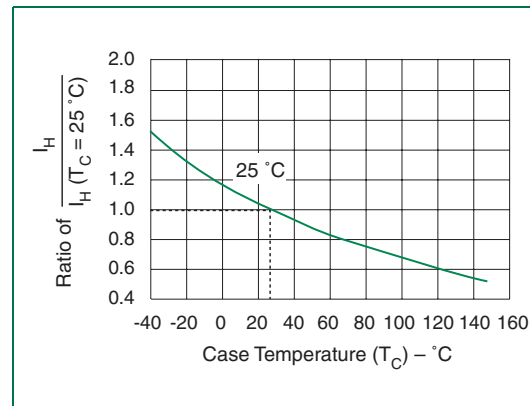
V-I Characteristics



$t_r \times t_d$ Pulse Waveform



Normalized V_S Change versus Junction Temperature



Normalized DC Holding Current versus Case Temperature